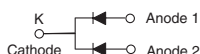


High Current Density Surface Mount Schottky Barrier Rectifier

eSMP™ Series



TO-277A (SMPC)



FEATURES

- Very low profile - typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal impedance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

AUTOMOTIVE
GRADE
Available



RoHS
COMPLIANT
HALOGEN
FREE

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 6.0 A
V_{RRM}	40 V
I_{FSM}	150 A
E_{AS}	20 mJ
V_F at $I_F = 6.0$ A	0.40 V
T_J max.	125 °C

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters and polarity protection applications.

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	SS12P4C	UNIT
Device marking code		S124C	
Maximum repetitive peak reverse voltage	V_{RRM}	40	V
Maximum average forward rectified current (fig. 1) ⁽¹⁾	$I_{F(AV)}$	12	A
		6.0	
Maximum average forward rectified current ⁽²⁾	$I_{F(AV)}$	3.5	A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150	A
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH per diode	E_{AS}	20	mJ
Peak repetitive reverse current at $t_p = 2$ μs, 1 kHz, at $T_J = 25$ °C per diode	I_{RRM}	1.0	A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 125	°C

Notes

⁽¹⁾ Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink

⁽²⁾ Free air, mounted on recommended copper pad area

SS12P4C

Vishay General Semiconductor

**ELECTRICAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 1\text{ A}$	$V_F^{(1)}$	0.34	-	V
	$I_F = 3\text{ A}$		0.40	-	
	$I_F = 6\text{ A}$		0.46	0.52	
	$I_F = 1\text{ A}$		0.24	-	
	$I_F = 3\text{ A}$		0.31	-	
	$I_F = 6\text{ A}$		0.40	0.45	
Reverse current per diode	Rated V_R	$I_R^{(2)}$	129	500	μA
			11.9	25	mA
Typical junction capacitance per diode	4.0 V, 1 MHz	C_J	400	-	pF

Notes(3) Pulse test: 300 μs pulse width, 1 % duty cycle(4) Pulse test: Pulse width $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	SS12P4C	UNIT
Typical thermal resistance	$R_{\theta JA}^{(1)}$	100	$^{\circ}\text{C/W}$
	$R_{\theta JM}^{(2)}$	3	

Notes(1) Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient.(2) Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink. Thermal resistance $R_{\theta JM}$ - junction to mount.**ORDERING INFORMATION** (Example)

PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS12P4C-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4C-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel
SS12P4CHM3/86A ⁽¹⁾	0.10	86A	1500	7" diameter plastic tape and reel
SS12P4CHM3/87A ⁽¹⁾	0.10	87A	6500	13" diameter plastic tape and reel

Note

(1) Automotive grade

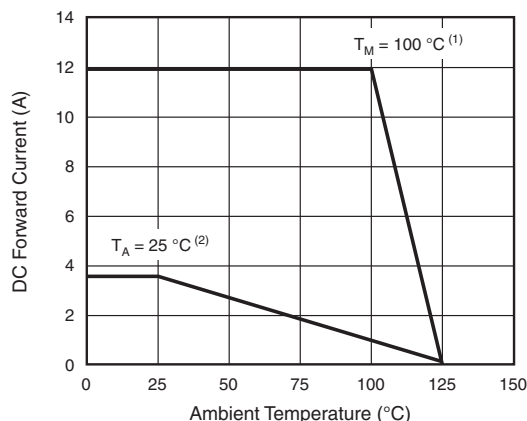
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

Notes

- Mounted on 30 mm x 30 mm Al PCB with 50 mm x 25 mm x 100 mm fin heat sink, T_M measured at the terminal of cathode band ($R_{\theta JM} = 3\text{ }^{\circ}\text{C/W}$)
- Free air, mounted on recommended copper pad area ($R_{\theta JA} = 100\text{ }^{\circ}\text{C/W}$)

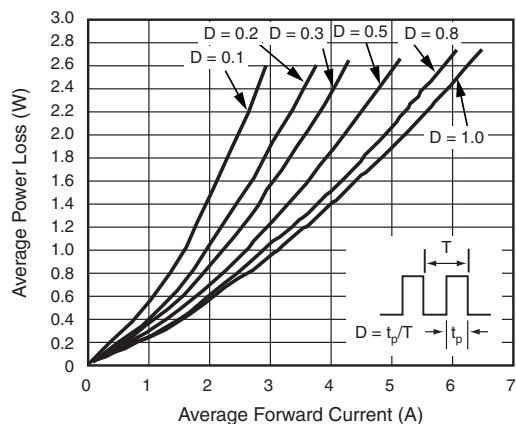


Fig. 2 - Forward Power Loss Characteristics Per Diode

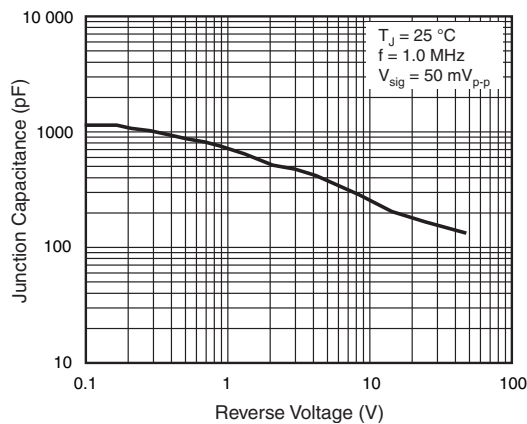


Fig. 5 - Typical Junction Capacitance Per Diode

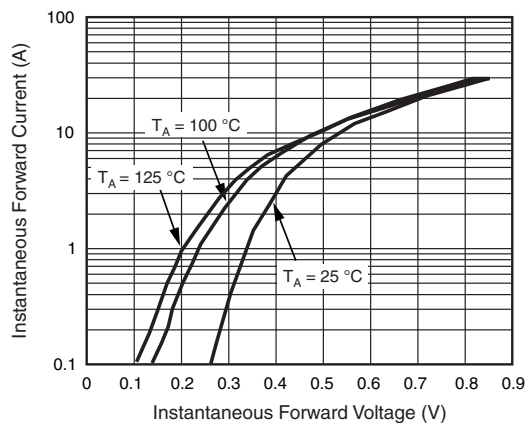


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

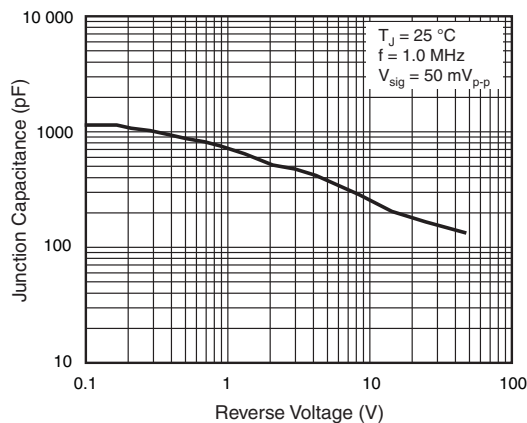


Fig. 6 - Typical Transient Thermal Impedance Per Diode

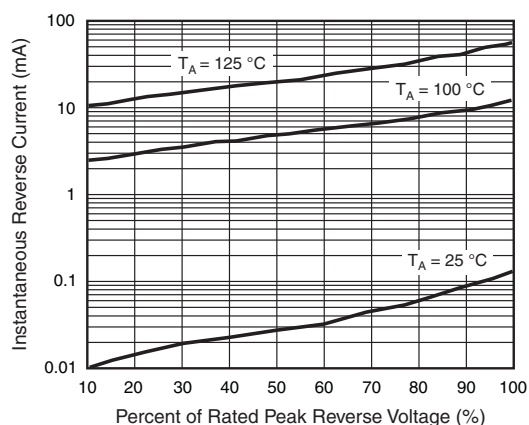
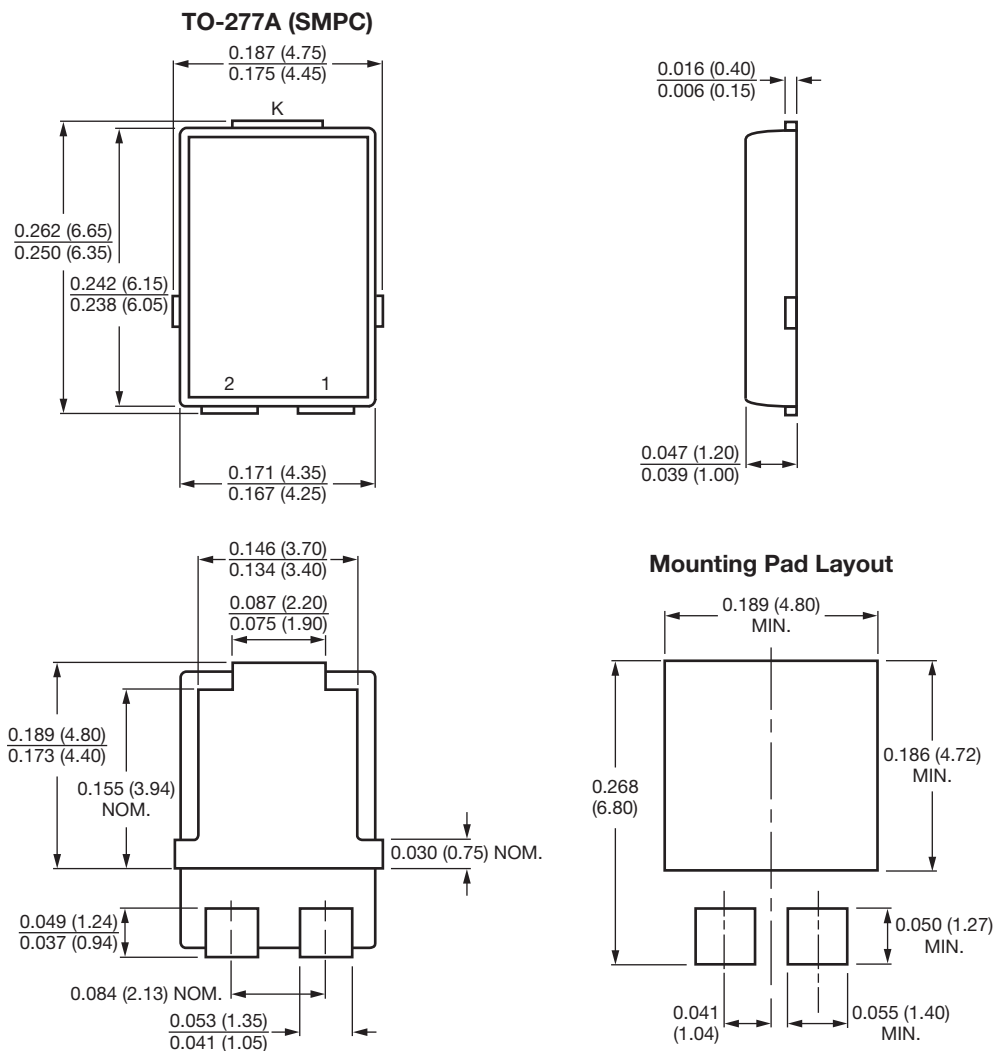


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

SS12P4C

Vishay General Semiconductor

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

Conform to JEDEC TO-277A



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9